









| | |
|---|---|
|  | <p>SI1305DL-T1-GE3</p> |
| | <p>Hersteller-Teilenummer: SI1305DL-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 8V 0.86A SC-70-3</p> <p>Datenblätter:  SI1305DL-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 39173 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|--|--|
| Teilenummer | SI1305DL-T1-GE3 |
| Hersteller | Vishay / Siliconix |
| Beschreibung | MOSFET P-CH 8V 0.86A SC-70-3 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 39173 pcs Stock |
| Serie | TrenchFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | SC-70, SOT-323 |
| Supplier Device-Gehäuse | SC-70-3 |
| Verlustleistung (max) | 290mW (Ta) |
| Typ FET | P-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 8V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 860mA (Ta) |
| Rds On (Max) @ Id, Vgs | 280 mOhm @ 1A, 4.5V |
| VGS (th) (Max) @ Id | 450mV @ 250µA (Min) |
| Gate Charge (Qg) (Max) @ Vgs | 4nC @ 4.5V |
| Eingabekapazität (Ciss) (Max) @ Vds | - |
| Verpackung | Original-Reel® |




























SI1305DL-T1-GE3 ist neu im Original. Suche SI1305DL-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1305DL-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1305DL-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|--|--|---|
|  <p>SI1305DL VISHAY SI1305DL VISHAY</p> |  <p>SI1305EDL VISHAY SI1305EDL VISHAY</p> |  <p>SI1305DL-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 8V 0.86A SC-70-3</p> |  <p>SI1305DL-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 8V 0.86A SOT323-3</p> |
|  <p>SI1305EDL-T1-E3 Vishay / Siliconix MOSFET P-CH 8V 0.86A SOT323-3</p> |  <p>SI1305EDL-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 8V 0.86A SOT323-3</p> |  <p>SI1305DL-T1-E3 Vishay / Siliconix MOSFET P-CH 8V 0.86A SOT323-3</p> |  <p>SI1305DL-T1-E2 VISHAY VISHAY SOT323</p> |

heiße Teile

Mehr

| | | | | |
|--|--|--|---|--|
|  SI1302DL |  SI1302DL-T1-E3 |  SI1302DL-T1-E3 |  SI1302DL-T1-GE3 |  SI1302DL-T1-GE3 |
|  SI1303DL |  SI1303DL-T1 |  SI1303DL-T1-E3 |  SI1303DL-T1-E3 |  SI1303DL-T1-GE3 |
|  SI1303DL-T1-GE3 |  SI1303DL-TL-E3 |  SI1303EDL-T1-GE3 |  SI1304BDL-T1-GE3 |  SI1304BDL-T1-GE3 |
|  SI1304DL |  SI1304DL-L |  SI1304DL-T1 |  SI1304DL-T1-E3 |  SI1304DL-T1-GE3 |
|  SI1305DL |  SI1305DL-T1 |  SI1305DL-T1-E3 |  SI1305DL-T1-E3 |  SI1305DL-T1-GE3 |
|  SI1305DL-T1-E3 |  SI1305EDL |  SI1305EDL-T1-E3 |  SI1305EDL-T1-E3 |  SI1305EDL-T1-GE3 |
|  SI1305EDL-T1-GE3 |  SI1305LT-T1-E3 |  SI1306DL |  SI1307-DL-T1-E3 |  SI1307DL |
|  SI1307DL-T1 |  SI1307DL-T1-E3 |  SI1307DL-T1-E3 |  SI1307DL-T1-GE3 |  SI1307DL-T1-GE3 |
|  SI1307EDL |  SI1307EDL-T1-E3 |  SI1307EDL-T1-E3 |  SI1307EDL-T1-GE3 |  SI1307EDL-T1-GE3 |
|  SI1308EDL |  SI1308EDL-T1-GE3 |  SI1308EDL-T1-GE3 |  SI13132CNU |  SI1315DL-T1-GE3 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited